

Thursday	
09:00	Exhibitors Setup
11:00	Registration & Exhibitors
11:45	Lunch & Coffee
12:45	Welcome
13:00	A1: M. Grashei "Thermal influence of interfaces in epitaxially grown superlattices"
13:15	A2: T. Tschirky "Scattering mechanisms of highest-mobility InAs/Al _x Ga _{1-x} Sb quantum wells"
13:30	A3: C. Deneke "Overgrowth study of back-bonded III-V semiconductor membranes"
13:45	A4: L. Prochaska "Epitaxial YbRh ₂ Si ₂ films grown by molecular beam epitaxy"
14:00	A5: A. Pawlis "Strain Compensation in ZnSe/CdSe Quantum Wells"
14:15	A6: M.P. Semtsiv "Growth... of Rhodium-doped InGaAs & InP by gas-source MBE"
14:30	Group Photo
15:00	Coffee
15:30	B1: J.-M. Chauveau "...Polar, Nonpolar and semipolar (Zn,Mg)O/ZnO...UV & THz applications"
15:45	B2: E. Hildebrandt "Control of Switching Modes & Conductance Quantization"
16:00	B3: R. Delgado "Towards GaN integration on Si: Microstructural study of ScN...on Si(111)"
16:15	B4: G. Calabrese : "MBE of GaN nanowires on flexible metal foils: challenges and prospects"
16:30	B5: S. Breuer "...Photoconductive THz Emitters & Detectors made of Fe-doped InGaAs"
16:45	B6: V.V. Volobuev "...Band Structure of PbSn Chalcogenide Topological Crystalline Insulators"
17:00	Poster Session
18:30	Bus 1 & 2 to Dinner
19:00	Dinner - Martin Sepp
21:30	Bus 1 back to Workshop Location
22:00	Bus 2 back to Workshop Location

Friday	
09:00	C1: E. Dimakis "GaAs-based core/shell nanowires ... grown on Si substrates"
09:15	C2: M.I. Lepsa "Self-catalyzed grown InAs/GaSb core-shell nanowire arrays"
09:30	C3: D. Ruhstorfer "Selective Area Epitaxy & Doping of Catalyst-Free GaAs Nanowires ..."
09:45	C4: T. Pejchal "...Ge nanowires: The co-effect of atomic hydrogen & catalyst spreading"
10:00	C5: E. T. Papaioannou "...Fe/Pt bilayers in optimizing the spin-pumping induced...emission"
10:15	C6: S. Gaucher "Magnetic Properties of Ferromagnet/Semiconductor/Ferromagnet..."
10:30	Coffee
11:00	D1: X. Y. Yuan "New Optical selection rules from GaAs quantum dots...stress actuators"
11:15	D2: H. Huang "Novel quantum optical devices based on doplet epitaxial GaAs/AlGaAs..."
11:30	D3: R. Keil "Solid-state ensemble of highly entangled photon sources at rubidium atomic ..."
11:45	D4: H. Groiss "Phase separation in metastable Ge _{1-x} Sn _x epilayers induced by...Sn precipitates"
12:00	D5: J. Falta "Initial growth of tin on silicon & germanium surfaces"
12:15	D6: J. Schmidt "Carbon-mediated epitaxy of SiGe virtual substrates on Si(001)"
12:30	Lunch & Coffee
13:30	Closing Remarks & Open Discussion
13:45	